Analog Power AM50P03-09D

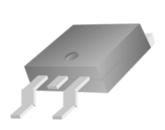
P-Channel 30-V (D-S) MOSFET

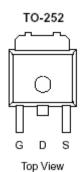
These miniature surface mount MOSFETs utilize High Cell Density process. Low r_{DS(on)} assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are PWMDC-DC converters, power management in portable and battery-powered products such as computers, printers, battery charger, telecommunication power system, and telephones power system.

•	Low r _{DS(on)} Provides Higher Efficiency and
	Extends Battery Life

- Miniature TO-252 Surface Mount Package Saves Board Space
- High power and current handling capability
- Extended VGS range (±25) for battery pack applications

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	I _D (A)		
-30	$9 @ V_{GS} = -10V$	61		
-30	$13 @ V_{GS} = -4.5V$	51		





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage			-30	V	
Gate-Source Voltage	V_{GS}	±25	V		
Continuous Drain Current ^a	$T_A=25^{\circ}C$	I_D	61	Α	
Pulsed Drain Current ^b	I_{DM}	±40	A		
Continuous Source Current (Diode Conduction) ^a		I_S	-30	A	
Power Dissipation ^a	$T_A=25^{\circ}C$	P_{D}	50	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	$R_{ heta JA}$	50	°C/W	
Maximum Junction-to-Case	$R_{ heta JC}$	3.0	°C/W	

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Donomotor	Crymbal	Tost Conditions	Limits			T I 4	
Parameter	Symbol	Symbol Test Conditions		Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250 \text{ uA}$	-1				
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 25 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	4	
Zero Gate Voltage Drain Current	1DSS	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-5	uA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-41			A	
D : G O D : A		$V_{GS} = -10 \text{ V}, I_D = -61 \text{ A}$			9	mΩ	
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -51 \text{ A}$			13	11122	
Forward Tranconductance ^A	g_{fs}	$V_{DS} = -15 \text{ V}, I_D = -61 \text{ A}$		31		S	
Diode Forward Voltage	V_{SD}	$I_S = -41 \text{ A}, V_{GS} = 0 \text{ V}$		-0.7		V	
Dynamic ^b							
Total Gate Charge	Q_{g}	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V},$		37.0			
Gate-Source Charge	Q_{gs}	$I_{DS} = -13 \text{ v}, \text{ v}_{GS} = -4.3 \text{ v},$ $I_{D} = -61 \text{ A}$		10.0		пC	
Gate-Drain Charge	Q_{gd}	1D01 A		14.5		1 !	
Switching							
Turn-On Delay Time	$t_{d(on)}$			15			
Rise Time	$t_{\rm r}$	$V_{DD} = -15 \text{ V}, R_L = 15 \Omega, ID = -41$		12		nS	
Turn-Off Delay Time	$t_{d(off)}$	A, $VGEN = -10 \text{ V}$, $RG = 6\Omega$		62		113	
Fall-Time	t_{f}			46			

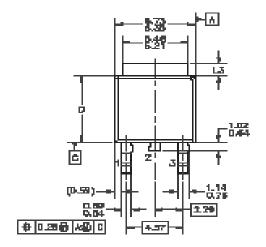
Notes

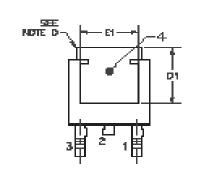
- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

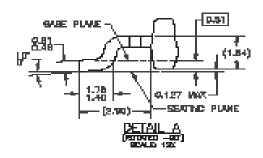
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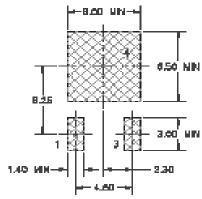
AM50P03-09D **Analog Power**

Package Information

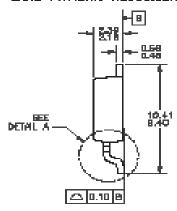








LAND PATTERN RECOMMENDATION



NOTES: UNLESS OTHERWISE SPECIFIED

- ALL DIPERSONS ARE IN ILLIMETERS.
 THIS PERSONCE CONFORMS TO JEDEC, TO-262,
 168ME C, VARIATION AA IN AB, DATED NOW 1989.
 DIMENSIONING AND TOLERANCING PER
- ASNE Y14-0M-1884.
 HEAT SINK TOP EDGE COULD BE IN CHANFERED CORRERS OR EDGE PROTEURION.
 DIMENSIONS 13,0,61-601 TABLE:

	CONTROL JAN	GETTION AND
	0.0 -1.27	1.62-7.09
		8.44-8.40
	4.42	3.81 MM
пп	7 1 7 1 1 1	4.47